

# 54F/74F651 ● 54F/74F652 Transceivers/Registers

## **General Description**

These devices consist of bus transceiver circuits with D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the input bus or from internal registers. Data on the A or B bus will be clocked into the registers as the appropriate clock pin goes to HIGH logic level. Output Enable pins (OEAB,  $\overline{\text{OEBA}}$ ) are provided to control the transceiver function.

#### **Features**

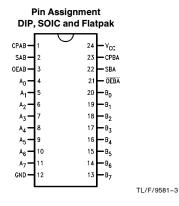
- Independent registers for A and B buses
- Multiplexed real-time and stored data
- Choice of non-inverting and inverting data paths
   'F651 inverting
  - 'F652 non-inverting
- Guaranteed 4000V minimum ESD protection

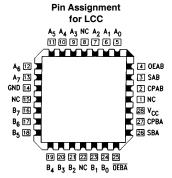
Commercial	Military	Package Number	Package Description		
74F651SPC		N24C	24-Lead (0.300" Wide) Molded Dual-In-Line		
	54F651SDM (Note 2)	J24F	24-Lead (0.300" Wide) Ceramic Dual-In-Line		
74F651SC (Note 1)		M24B	24-Lead (0.300" Wide) Molded Small Outline, JEDEC		
	54F651FM (Note 2)	W24C	24-Lead Cerpack		
	54F651LM (Note 2)	E28A	24-Lead Ceramic Leadless Chip Carrier, Type C		
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	54F652LM (Note 2)	E28A	24-Lead Ceramic Leadless Chip Carrier, Type C		

Note 1:Devices also available in 13" reel. Use suffix = SCX

Note 2:Military grade device with environmental and burn-in processing. Use suffix = DMQB, FMQB and LMQB

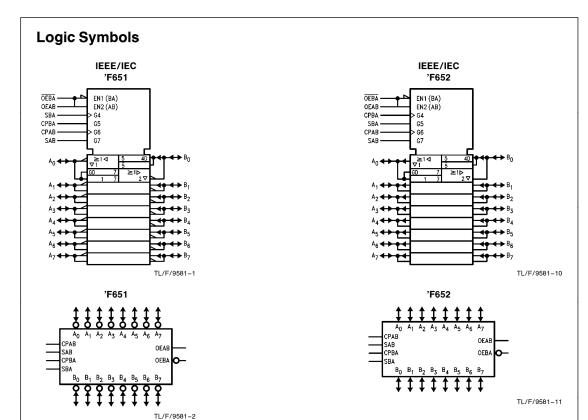
#### **Connection Diagrams**





TL/F/9581-4

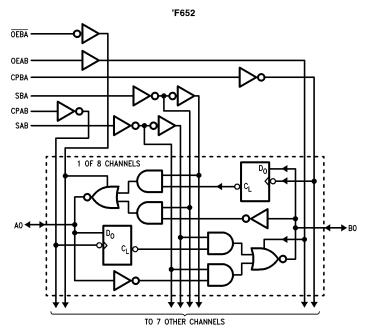
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## **Unit Loading/Fan Out**

		54F/74F				
Pin Names	Description	U.L. HIGH/LOW	Input I <sub>IH</sub> /I <sub>IL</sub> Output I <sub>OH</sub> /I <sub>OL</sub>			
A <sub>0</sub> -A <sub>7</sub> , B <sub>0</sub> -B <sub>7</sub>	A and B Inputs/ TRI-STATE® Outputs	1.0/1.0 600/106.6 (80)	20 μA/ - 0.6 mA -12 mA/64 mA (48 mA)			
CPAB, CPBA	Clock Inputs	1.0/1.0	20 μA/ - 0.6 mA			
SAB, SBA	Select Inputs	1.0/1.0	20 μA/ – 0.6 mA			
OEAB, OEBA	Output Enable Inputs	1.0/1.0	20 μA/ - 0.6 mA			

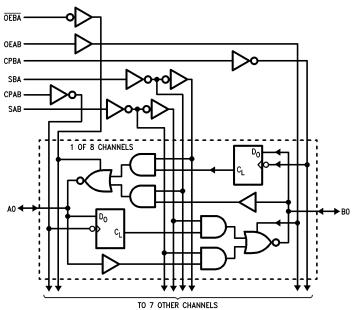
# **Logic Diagrams**



TL/F/9581-5

Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

## 'F651



TL/F/9581-12

Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

### **Functional Description**

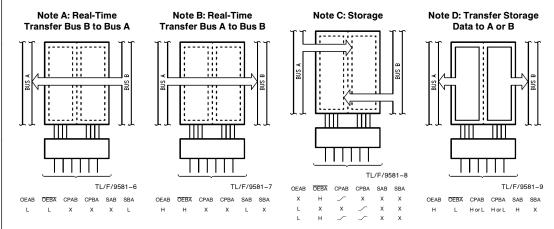
In the transceiver mode, data present at the HIGH impedance port may be stored in either the A or B register or both.

The select (SAB, SBA) controls can multiplex stored and real-time.

The examples in *Figure 1* demonstrate the four fundamental bus-management functions that can be performed with the Octal bus transceivers and receivers.

Data on the A or B data bus, or both can be stored in the internal D flip-flop by LOW to HIGH transitions at the appro-

priate Clock Inputs (CPAB, CPBA) regardless of the Select or Output Enable Inputs. When SAB and SBA are in the real time transfer mode, it is also possible to store data without using the internal D flip-flops by simultaneously enabling OEAB and OEBA. In this configuration each Output reinforces its Input. Thus when all other data sources to the two sets of bus lines are in a HIGH impedance state, each set of bus lines will remain at its last state.



#### FIGURE 1

Inputs						Inputs/Outputs (Note 1)		Operating Mode	
OEAB	OEBA	СРАВ	СРВА	SAB	SBA	A <sub>0</sub> thru A <sub>7</sub>	B <sub>0</sub> thru B <sub>7</sub>		
L	Н	H or L	H or L	X	х	Input	Input	Isolation	
L	Н			X	х	Прис	При	Store A and B Data	
X	Н		H or L	Х	Х	Input	Not Specified	Store A, Hold B	
Н	Н			X	Х	Input	Output	Store A in Both Registers	
L	Х	H or L		X	Х	Not Specified	Input	Hold A, Store B	
L	L			Х	Х	Output	Input	Store B in Both Registers	
L	L	Х	Х	X	L	Output	Input	Real-Time B Data to A Bus	
L	L	Х	H or L	Х	Н	Output	При	Store B Data to A Bus	
Н	Н	Х	Х	L	Х	Input	Output	Real-Time A Data to B Bus	
Н	Н	H or L	Х	Н	Х	При	Catput	Stored A Data to B Bus	
Н	L	H or L	H or L	Н	Н	Output	Output	Stored A Data to B Bus and Stored B Data to A Bus	

H = HIGH Voltage Level

Note 1: The data output functions may be enabled or disabled by various signals at OEAB or OEBA inputs. Data input functions are always enabled, i.e., data at the bus pins will be stored on every LOW to HIGH transition on the clock inputs.

L = LOW Voltage Level

X = Immaterial

<sup>✓ =</sup> LOW to HIGH Clock Transition

### **Absolute Maximum Ratings** (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

-65°C to +150°C Storage Temperature Ambient Temperature under Bias -55°C to +125°C Junction Temperature under Bias -55°C to +175°C -55°C to +150°C

V<sub>CC</sub> Pin Potential to

Ground Pin -0.5V to +7.0V

Input Voltage (Note 2) -0.5V to +7.0VInput Current (Note 2) -30 mA to +5.0 mA

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under

these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

Voltage Applied to Output in HIGH State (with  $V_{CC} = 0V$ )

- 0.5V to V $_{\rm CC}$  - 0.5V to + 5.5V Standard Output TRI-STATE Output

Current Applied to Output

in LOW State (Max) twice the rated  $I_{OL}$  (mA) ESD Last Passing Voltage (Min) 4000V

## **Recommended Operating** Conditions

Free Air Ambient Temperature

Military -55°C to +125°C Commercial  $0^{\circ}C$  to  $+70^{\circ}C$ 

Supply Voltage

Military  $+\,4.5V$  to  $+\,5.5V$ Commercial +4.5V to +5.5V

### **DC Electrical Characteristics**

Symbol	Parameter .		54F/74F			Units	V	Conditions	
Syllibol			Min	Тур	Max	Uiiiis	V <sub>CC</sub>	Conditions	
V <sub>IH</sub>	Input HIGH Voltage		2.0			٧		Recognized as a HIGH Signal	
V <sub>IL</sub>	Input LOW Voltage				0.8	٧		Recognized as a LOW Signal	
V <sub>CD</sub>	Input Clamp Diode Vo	oltage			-1.2	V	Min	$I_{IN} = -18 \text{ mA (Non I/O Pins)}$	
V <sub>OH</sub>	Output HIGH Voltage	54F 10% V <sub>CC</sub> 74F 10% V <sub>CC</sub>	2.0 2.0			٧	Min	$I_{OH} = -12 \text{ mA } (A_n, B_n)$ $I_{OH} = -15 \text{ mA } (A_n, B_n)$	
V <sub>OL</sub>	Output LOW Voltage	54F 10% V <sub>CC</sub> 74F 10% V <sub>CC</sub>			0.55 0.55	٧	Min	$I_{OL} = 48 \text{ mA } (A_n, B_n)$ $I_{OL} = 64 \text{ mA } (A_n, B_n)$	
I <sub>IH</sub>	Input HIGH Current	54F 74F			20.0 5.0	μΑ	Max	V <sub>IN</sub> = 2.7V (Non I/O Pins)	
I <sub>BVI</sub>	Input HIGH Current Breakdown Test	54F 74F			100 7.0	μΑ	Max	V <sub>IN</sub> = 7.0V	
I <sub>BVIT</sub>	Input HIGH Current Breakdown (I/O)	54F 74F			1.0 0.5	mA	Max	V <sub>IN</sub> = 5.5V (A <sub>n</sub> , B <sub>n</sub> )	
I <sub>CEX</sub>	Output HIGH Leakage Current	54F 74F			250 50	μΑ	Max	V <sub>OUT</sub> = V <sub>CC</sub>	
V <sub>ID</sub>	Input Leakage Test	74F	4.75			٧	0.0	$I_{\text{ID}} = 1.9  \mu\text{A}$ All Other Pins Grounded	
I <sub>OD</sub>	Output Leakage Circuit Current	74F			3.75	μΑ	0.0	VI <sub>IOD</sub> = 150 mV All Other Pins Grounded	
I <sub>IL</sub>	Input LOW Current				-0.6	mA	Max	V <sub>IN</sub> = 0.5V (Non I/O Pins)	
I <sub>IH</sub> + I <sub>OZH</sub>	Output Leakage Curr	ent			70	μΑ	Max	$V_{OUT} = 2.7V (A_n, B_n)$	
I <sub>IL</sub> + I <sub>OZL</sub>	Output Leakage Current				-650	μΑ	Max	$V_{OUT} = 0.5V (A_n, B_n)$	
los	Output Short-Circuit Current		-100		-225	mA	Max	V <sub>OUT</sub> = 0V	
I <sub>ZZ</sub>	Bus Drainage Test				500	μΑ	0.0V	V <sub>OUT</sub> = 5.25V	
Іссн	Power Supply Current			105	135	mA	Max	V <sub>O</sub> = HIGH	
ICCL	Power Supply Current			118	150	mA	Max	V <sub>O</sub> = LOW	
lccz	Power Supply Curren	t		115	150	mA	Max	V <sub>O</sub> = HIGH Z	

## **AC Electrical Characteristics**

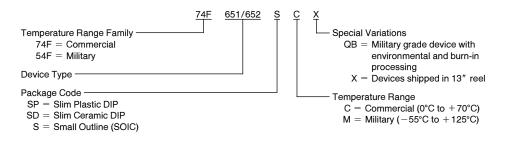
Symbol	Parameter	74F  T <sub>A</sub> = +25°C  V <sub>CC</sub> = +5.0V  C <sub>L</sub> = 50 pF		54F  T <sub>A</sub> , V <sub>CC</sub> = Mil C <sub>L</sub> = 50 pF		74F  T <sub>A</sub> , V <sub>CC</sub> = Com C <sub>L</sub> = 50 pF		Units
		Min	Max	Min	Max	Min	Max	
f <sub>max</sub>	Max. Clock Frequency	90		75		90		MHz
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay Clock to Bus	2.0 2.0	7.0 8.0	2.0 2.0	8.5 9.5	2.0 2.0	8.0 9.0	ns
t <sub>PLH</sub>	Propagation Delay Bus to Bus ('F651)	2.0 1.0	8.5 7.5	1.0 1.0	9.0 8.0	2.0 1.0	9.0 8.0	ns
t <sub>PLH</sub>	Propagation Delay Bus to Bus ('F652)	1.0 1.0	7.0 6.5	1.0 1.0	8.0 8.0	1.0 1.0	7.5 7.0	ns
t <sub>PLH</sub>	Propagation Delay SBA or SAB to A or B	2.0 2.0	8.5 8.0	2.0 2.0	11.0 10.0	2.0 2.0	9.5 9.0	ns

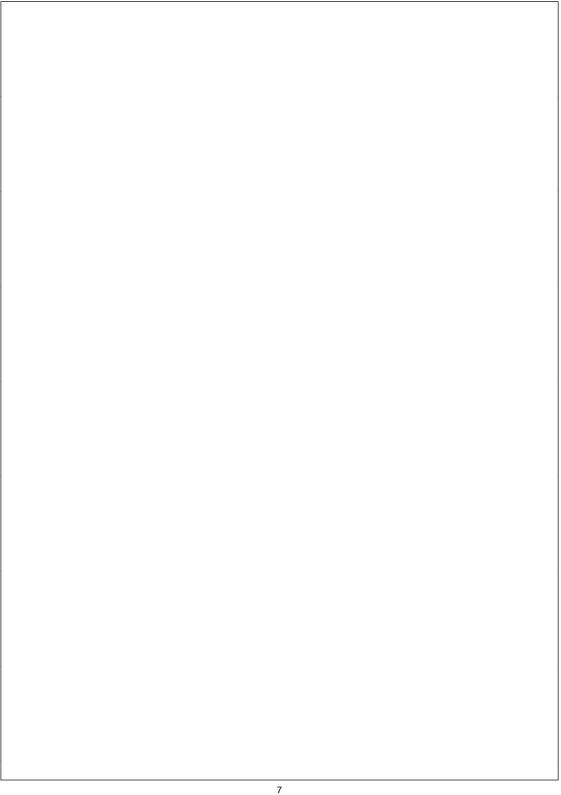
## **AC Operating Requirements**

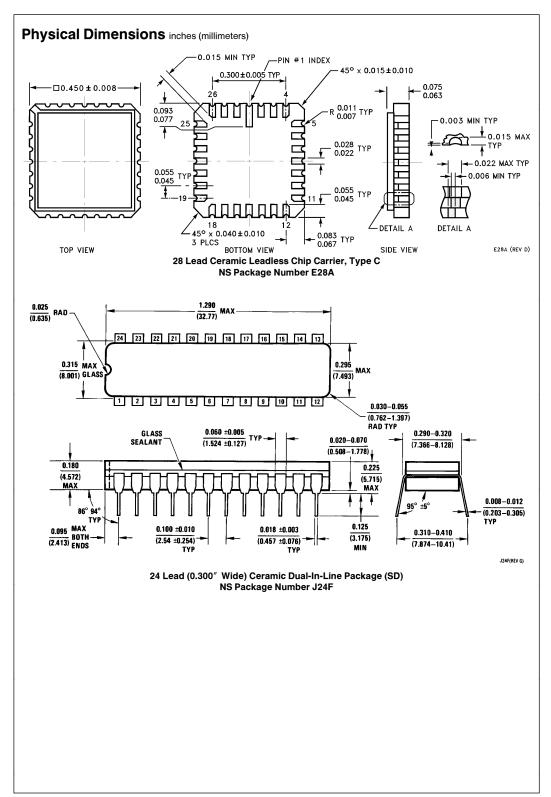
		74F T <sub>A</sub> = +25°C V <sub>CC</sub> = +5.0V		54	F	74F  T <sub>A</sub> , V <sub>CC</sub> = Com		Units
Symbol	Parameter			T <sub>A</sub> , V <sub>CC</sub>	; = Mil			
		Min	Max	Min	Max	Min	Max	
t <sub>PZH</sub>	Enable Time *OEBA to A	2.0 2.0	9.5 12.0	2.0 2.0	10.0 10.0	2.0 2.0	10.0 12.5	
t <sub>PHZ</sub>	Disable Time *OEBA to A	1.0 2.0	7.5 8.5	1.0 1.0	9.0 9.0	1.0 2.0	8.0 9.0	ns
t <sub>PZH</sub>	Enable Time OEAB to B	2.0 3.0	9.5 13.0	2.0 2.0	10.0 12.0	2.0 3.0	10.0 14.0	
t <sub>PHZ</sub>	Disable Time OEAB to B	2.0 2.0	9.0 10.5	1.0 1.0	9.0 12.0	2.0 2.0	10.0 11.0	ns
t <sub>s</sub> (H)	Setup Time, HIGH or LOW, Bus to Clock	5.0 5.0		5.0 5.0		5.0 5.0		ns
t <sub>h</sub> (H)	Hold Time, HIGH or LOW, Bus to Clock	2.0 2.0		2.5 2.5		2.0 2.0		ns
t <sub>w</sub> (H)	Clock Pulse Width HIGH or LOW	5.0 5.0		5.0 5.0		5.0 5.0		ns

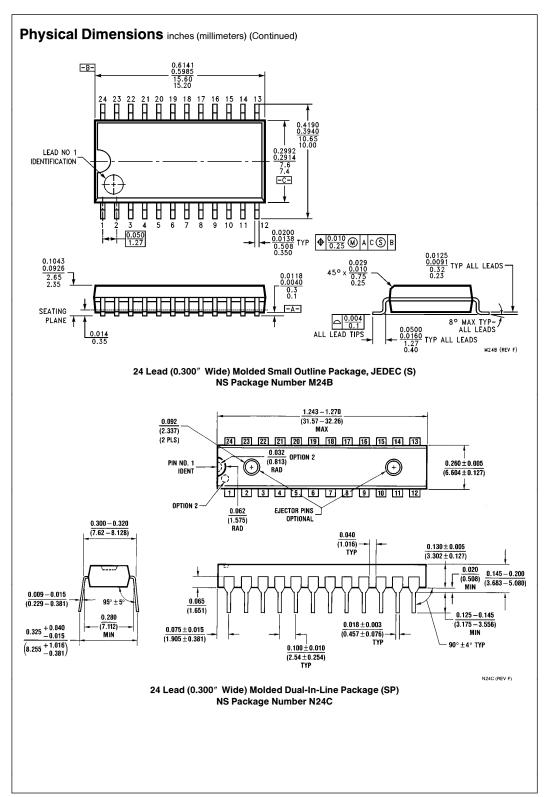
## Ordering Information

The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:

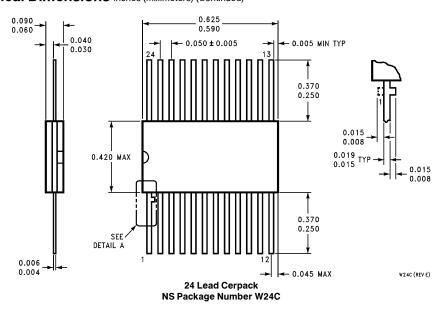








## Physical Dimensions inches (millimeters) (Continued)



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